

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TMCS1126A1AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A1A
TMCS1126A1AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A1A
TMCS1126A1BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A1B
TMCS1126A1BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A1B
TMCS1126A2AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A2A
TMCS1126A2AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A2A
TMCS1126A2BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A2B
TMCS1126A2BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A2B
TMCS1126A3AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A3A
TMCS1126A3AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A3A
TMCS1126A3BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A3B
TMCS1126A3BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A3B
TMCS1126A4AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A4A
TMCS1126A4AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A4A
TMCS1126A4BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A4B
TMCS1126A4BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A4B
TMCS1126A5AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A5A
TMCS1126A5AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A5A
TMCS1126A5BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A5B
TMCS1126A5BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A5B
TMCS1126A7AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A7A
TMCS1126A7AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A7A
TMCS1126A7BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A7B
TMCS1126A7BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A7B
TMCS1126A8AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A8A
TMCS1126A8AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A8A
TMCS1126A8BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A8B
TMCS1126A8BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126A8B
TMCS1126ADAQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126ADA

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TMCS1126B1AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B1A
TMCS1126B1AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B1A
TMCS1126B1BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B1B
TMCS1126B1BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B1B
TMCS1126B2AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B2A
TMCS1126B2AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B2A
TMCS1126B2BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B2B
TMCS1126B2BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B2B
TMCS1126B3AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B3A
TMCS1126B3AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B3A
TMCS1126B3BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B3B
TMCS1126B3BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B3B
TMCS1126B4AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B4A
TMCS1126B4AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B4A
TMCS1126B4BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B4B
TMCS1126B4BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B4B
TMCS1126B5AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B5A
TMCS1126B5AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B5A
TMCS1126B5BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B5B
TMCS1126B5BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B5B
TMCS1126B6AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B6A
TMCS1126B6AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B6A
TMCS1126B6BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B6B
TMCS1126B6BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B6B
TMCS1126B6BQDVGR.B	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TMCS1126B9AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B9A
TMCS1126B9AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B9A
TMCS1126B9BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B9B
TMCS1126B9BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126B9B
TMCS1126BAAQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126BAA
TMCS1126BAAQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126BAA

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TMCS1126BABQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126BAB
TMCS1126BABQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126BAB
TMCS1126BEBQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126BEB
TMCS1126BFAQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126BFA
TMCS1126C1AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C1A
TMCS1126C1AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C1A
TMCS1126C1BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C1B
TMCS1126C1BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C1B
TMCS1126C2AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C2A
TMCS1126C2AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C2A
TMCS1126C2BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C2B
TMCS1126C2BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C2B
TMCS1126C3AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C3A
TMCS1126C3AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C3A
TMCS1126C3BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C3B
TMCS1126C3BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C3B
TMCS1126C4AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C4A
TMCS1126C4AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C4A
TMCS1126C4BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C4B
TMCS1126C4BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C4B
TMCS1126C5AQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C5A
TMCS1126C5AQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C5A
TMCS1126C5BQDVGR	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C5B
TMCS1126C5BQDVGR.A	Active	Production	SOIC (DVG) 10	2000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	1126C5B

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TMCS1126 :

- Automotive : [TMCS1126-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects